





50V NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Ultra-Small Leadless Surface Mount Package
- Complementary PNP Type Available (2DA1774QLP)
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free, "Green" Device (Note 2)
- Qualified to AEC-Q101Standards for High Reliability

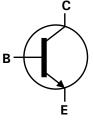
Mechanical Data

- Case: DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.0008 grams (approximate)

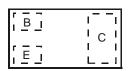
DFN1006-3



Bottom View



Device Symbol



Top View Device Schematic

Ordering Information (Note 3)

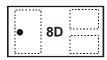
| Product | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|---------------|---------|--------------------|-----------------|-------------------|
| 2DC4617QLP-7 | 8D | 7 | 8 | 3,000 |
| 2DC4617QLP-7B | 8D | 7 | 8 | 10.000 |

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com.
- 3. For packaging details, go to our website at http://www.diodes.com.

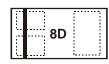
Marking Information

2DC4617QLP-7



Top View Dot Denotes Collector Side

2DC4617QLP-7B



Top View Bar Denotes Base and Emitter Side

8D = Product Type Marking Code



Maximum Ratings @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Unit |
|--------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | 50 | V |
| Collector-Emitter Voltage | V _{CEO} | 50 | V |
| Emitter-Base Voltage | V _{EBO} | 5.0 | V |
| Collector Current - Continuous | Ic | 100 | mA |
| Peak Collector Current | I _{CM} | 200 | mA |

Thermal Characteristics @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 4) | P_{D} | 250 | mW |
| Thermal Resistance, Junction to Ambient (Note 4) | $R_{	hetaJA}$ | 500 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics @T_A = 25°C unless otherwise specified

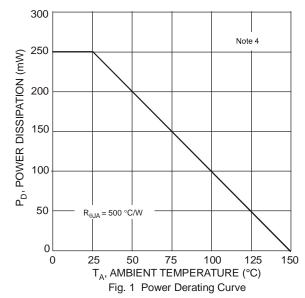
| Characteristic | Symbol | Min | Max | Unit | Test Condition |
|--------------------------------------|----------------------|-----|-----|------|--|
| OFF CHARACTERISTICS (Note 5) | | | | | |
| Collector-Base Breakdown Voltage | V _{(BR)CBO} | 50 | _ | V | $I_C = 50\mu A, I_E = 0$ |
| Collector-Emitter Breakdown Voltage | V _{(BR)CEO} | 50 | _ | V | $I_C = 1.0 \text{mA}, I_B = 0$ |
| Emitter-Base Breakdown Voltage | V _{(BR)EBO} | 5.0 | _ | V | $I_E = 50 \mu A, I_C = 0$ |
| Collector Cutoff Current | | _ | 100 | nA | V _{CB} = 30V |
| Collector Cutoff Current | Ісво | | 5 | μΑ | $V_{CB} = 30V, T_A = 150^{\circ}C$ |
| Emitter Cutoff Current | I _{EBO} | _ | 100 | nA | $V_{EB} = 4.0V$ |
| ON CHARACTERISTICS (Note 5) | | | | | |
| DC Current Gain | h _{FE} | 120 | 270 | _ | $V_{CE} = 6.0V, I_{C} = 1.0mA$ |
| Collector-Emitter Saturation Voltage | V _{CE(SAT)} | _ | 0.2 | V | $I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$ |
| SMALL SIGNAL CHARACTERISTICS | | | | | |
| Output Capacitance | C _{obo} | _ | 3.5 | pF | $V_{CB} = 12V, f = 1.0MHz, I_E = 0$ |
| Current Gain-Bandwidth Product | f⊤ | 100 | _ | MHz | $V_{CE} = 12V, I_{C} = 2.0 \text{mA},$ f = 100MHz |

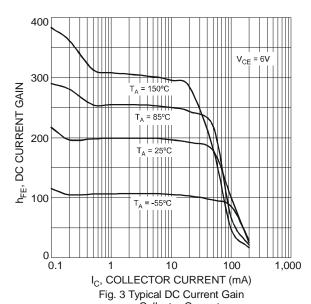
Notes:

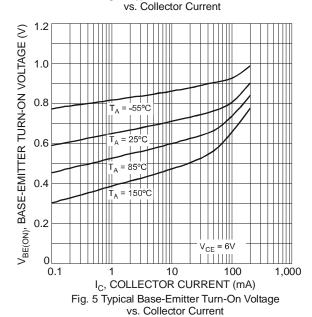
- 4. Part mounted on FR-4 PCB with recommended pad layout.5. Short duration pulse test used to minimize self-heating effect.

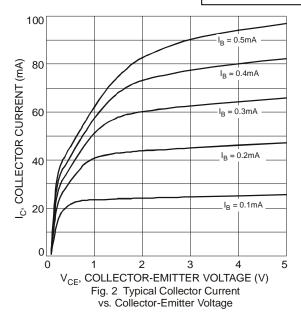












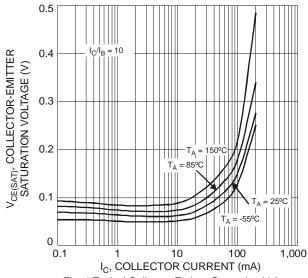


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

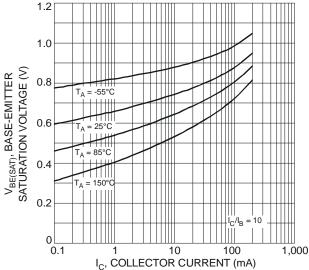
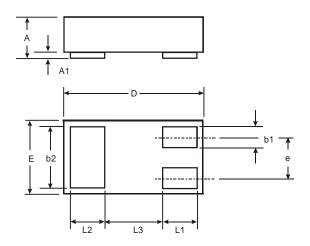


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

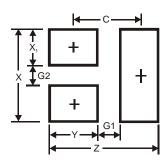


Package Outline Dimensions



| DFN1006-3 | | | | | | |
|-----------|----------------------|-------|------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 0.47 | 0.53 | 0.50 | | | |
| A1 | 0 | 0.05 | 0.03 | | | |
| b1 | 0.10 | 0.20 | 0.15 | | | |
| b2 | 0.45 | 0.55 | 0.50 | | | |
| D | 0.95 | 1.075 | 1.00 | | | |
| Е | 0.55 | 0.675 | 0.60 | | | |
| е | _ | _ | 0.35 | | | |
| L1 | 0.20 | 0.30 | 0.25 | | | |
| L2 | 0.20 | 0.30 | 0.25 | | | |
| L3 | _ | _ | 0.40 | | | |
| All | All Dimensions in mm | | | | | |

Suggested Pad Layout



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 1.1 |
| G1 | 0.3 |
| G2 | 0.2 |
| Х | 0.7 |
| X1 | 0.25 |
| Y | 0.4 |
| С | 0.7 |



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